



## Description

The FDS6673AZ uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

## General Features

$V_{DS} = -30V$   $I_D = -15A$

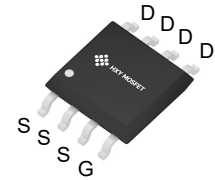
$R_{DS(ON)} < 8.7m\Omega$  @  $V_{GS}=10V$

## Application

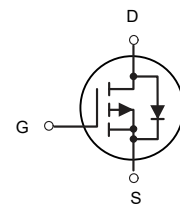
Battery protection

Load switch

Uninterruptible power supply



SOP-8  
(SO-8)



P-Channel MOSFET

## Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
FDS6673AZ	SOP-8(SO-8)	HXY MOSFET	3000

## Absolute Maximum Ratings ( $T_C=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Rating	Units
$V_{DS}$	Drain-Source Voltage	-30	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D@T_A=25^\circ C$	Continuous Drain Current, $V_{GS}$ @ -10V <sup>1</sup>	-15	A
$I_D@T_A=70^\circ C$	Continuous Drain Current, $V_{GS}$ @ -10V <sup>1</sup>	-11	A
$I_{DM}$	Pulsed Drain Current <sup>2</sup>	-56	A
EAS	Single Pulse Avalanche Energy <sup>3</sup>	151	mJ
$I_{AS}$	Avalanche Current	-55	A
$P_D@T_A=25^\circ C$	Total Power Dissipation <sup>4</sup>	1.5	W
$T_{STG}$	Storage Temperature Range	-55 to 150	$^\circ C$
$T_J$	Operating Junction Temperature Range	-55 to 150	$^\circ C$
$R_{\theta JA}$	Thermal Resistance Junction-Ambient <sup>1</sup> ( $t \leq 10s$ )	40	$^\circ C/W$
	Thermal Resistance Junction-Ambient <sup>1</sup>	75	$^\circ C/W$
$R_{\theta JC}$	Thermal Resistance Junction-Case <sup>1</sup>	24	$^\circ C/W$



**Electrical Characteristics ( $T_J=25^{\circ}\text{C}$ , unless otherwise noted)**

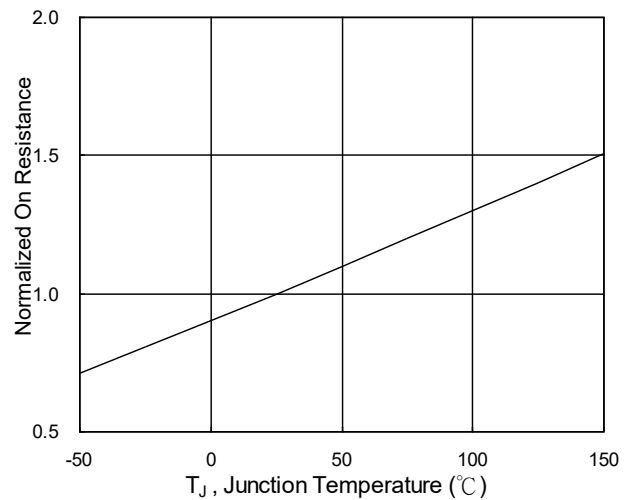
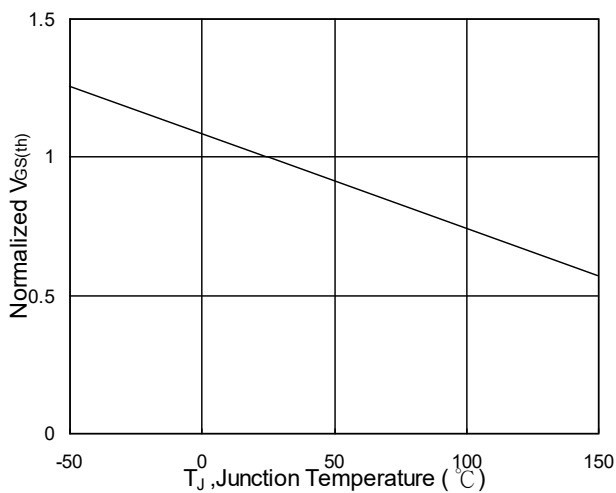
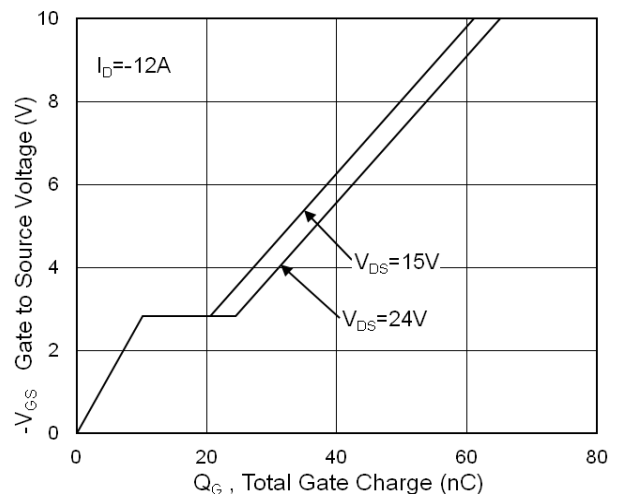
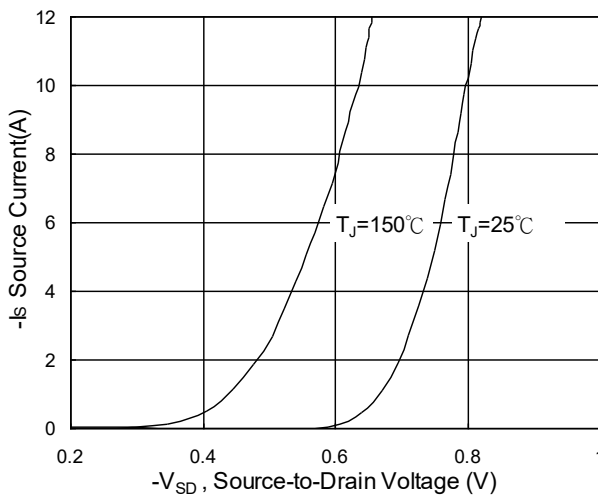
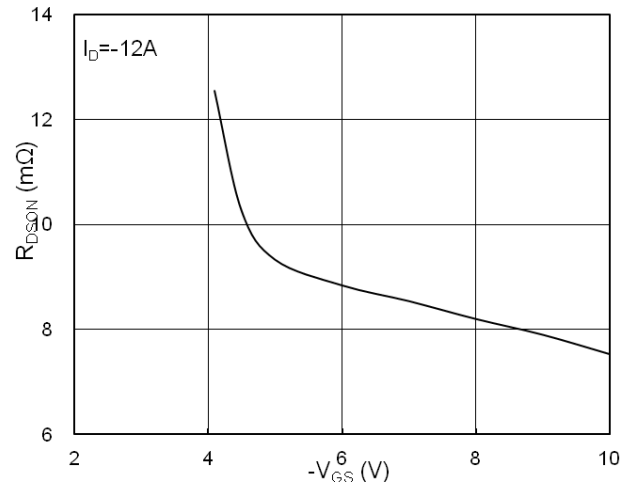
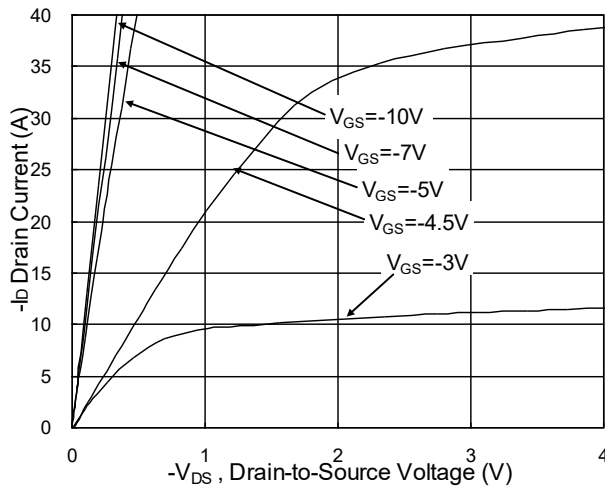
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V$ , $I_D=-250\mu A$	-30	---	---	V
$\Delta BV_{DSS}/\Delta T_J$	$BV_{DSS}$ Temperature Coefficient	Reference to $25^{\circ}\text{C}$ , $I_D=-1\text{mA}$	---	-0.018	---	$V/^{\circ}\text{C}$
$R_{DS(on)}$	Static Drain-Source On-Resistance <sup>2</sup>	$V_{GS}=-10V$ , $I_D=-12A$	---	5.8	8.7	$m\Omega$
		$V_{GS}=-4.5V$ , $I_D=-10A$	---	8.5	13.5	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS}=V_{DS}$ , $I_D=-250\mu A$	-1.2	---	-2.5	V
$\Delta V_{GS(th)}$	$V_{GS(th)}$ Temperature Coefficient		---	5.04	---	$mV/^{\circ}\text{C}$
$I_{DSS}$	Drain-Source Leakage Current	$V_{DS}=-24V$ , $V_{GS}=0V$ , $T_J=25^{\circ}\text{C}$	---	---	-1	$\mu A$
		$V_{DS}=-24V$ , $V_{GS}=0V$ , $T_J=55^{\circ}\text{C}$	---	---	-5	
$I_{GSS}$	Gate-Source Leakage Current	$V_{GS}=\pm 20V$ , $V_{DS}=0V$	---	---	$\pm 100$	nA
$g_{fs}$	Forward Transconductance	$V_{DS}=-5V$ , $I_D=-12A$	---	25	---	S
$Q_g$	Total Gate Charge (-4.5V)	$V_{DS}=-15V$ , $V_{GS}=-4.5V$ , $I_D=-12A$	---	30	---	nC
$Q_{gs}$	Gate-Source Charge		---	10	---	
$Q_{gd}$	Gate-Drain Charge		---	10.4	---	
$T_{d(on)}$	Turn-On Delay Time	$V_{DD}=-15V$ , $V_{GS}=-10V$ , $R_G=3.3\Omega$ , $I_D=-1A$	---	9.4	---	ns
$T_r$	Rise Time		---	10.2	---	
$T_{d(off)}$	Turn-Off Delay Time		---	117	---	
$T_f$	Fall Time		---	24	---	
$C_{iss}$	Input Capacitance	$V_{DS}=-15V$ , $V_{GS}=0V$ , $f=1\text{MHz}$	---	3448	---	pF
$C_{oss}$	Output Capacitance		---	508	---	
$C_{rss}$	Reverse Transfer Capacitance		---	421	---	
$I_S$	Continuous Source Current <sup>1,5</sup>	$V_G=V_D=0V$ , Force Current	---	---	-14	A
$I_{SM}$	Pulsed Source Current <sup>2,5</sup>		---	---	-56	A
$V_{SD}$	Diode Forward Voltage <sup>2</sup>	$V_{GS}=0V$ , $I_S=-1A$ , $T_J=25^{\circ}\text{C}$	---	---	-1.2	V
$t_{rr}$	Reverse Recovery Time	$I_F=-10A$ , $dI/dt=100A/\mu s$ , $T_J=25^{\circ}\text{C}$	---	19.4	---	nS
$Q_{rr}$	Reverse Recovery Charge		---	9.1	---	nC

Note :

- 1.The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width  $\leq 300\mu s$  , duty cycle  $\leq 2\%$
- 3.The EAS data shows Max. rating . The test condition is  $V_{DD}=-25V$ ,  $V_{GS}=-10V$ ,  $L=0.1\text{mH}$ ,  $I_{AS}=-55A$
- 4.The power dissipation is limited by  $150^{\circ}\text{C}$  junction temperature
- 5.The data is theoretically the same as  $I_D$  and  $I_{DM}$  , in real applications , should be limited by total power dissipation.



## Typical Characteristics



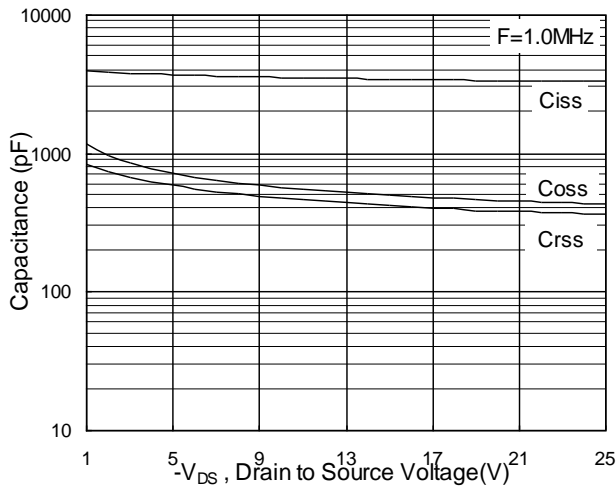


Fig.7 Capacitance

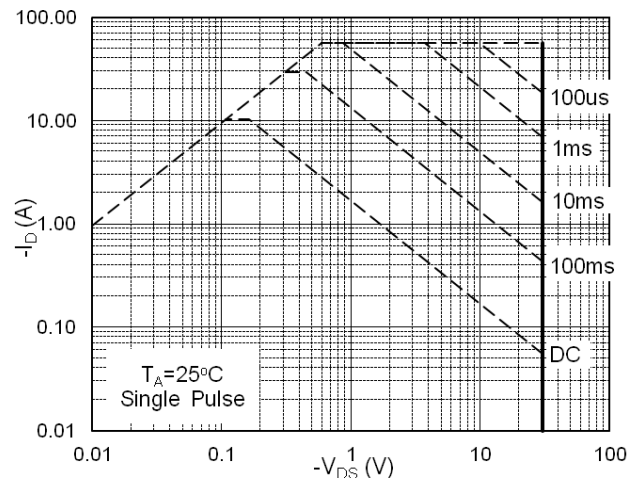


Fig.8 Safe Operating Area

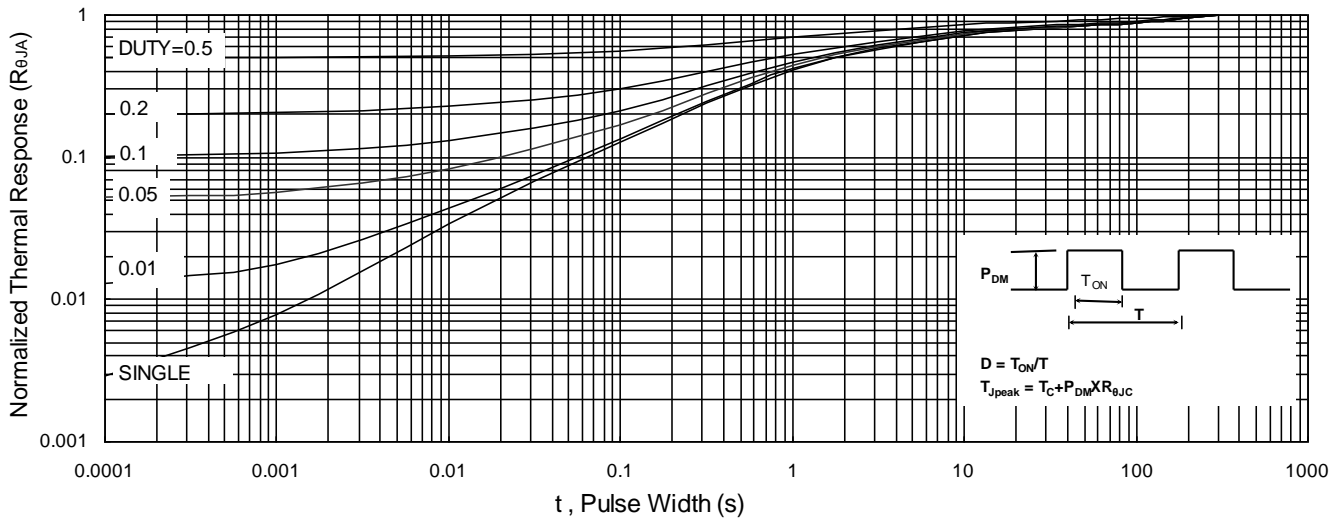


Fig.9 Normalized Maximum Transient Thermal Impedance

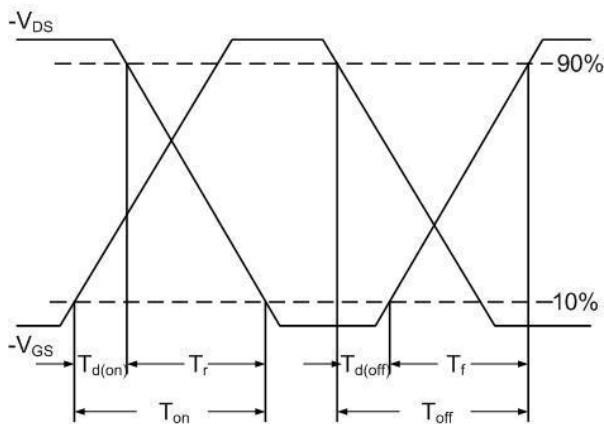


Fig.10 Switching Time Waveform

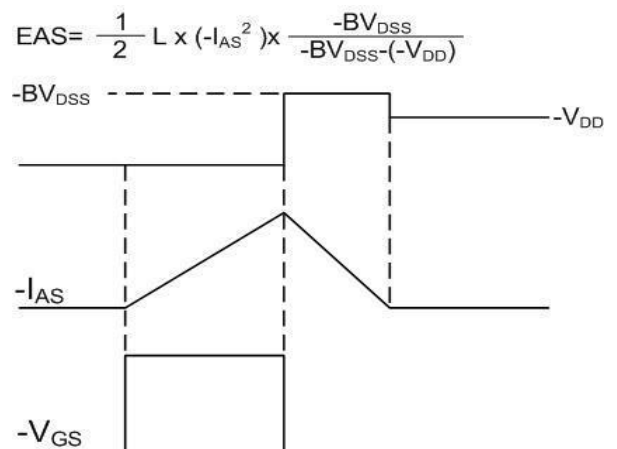
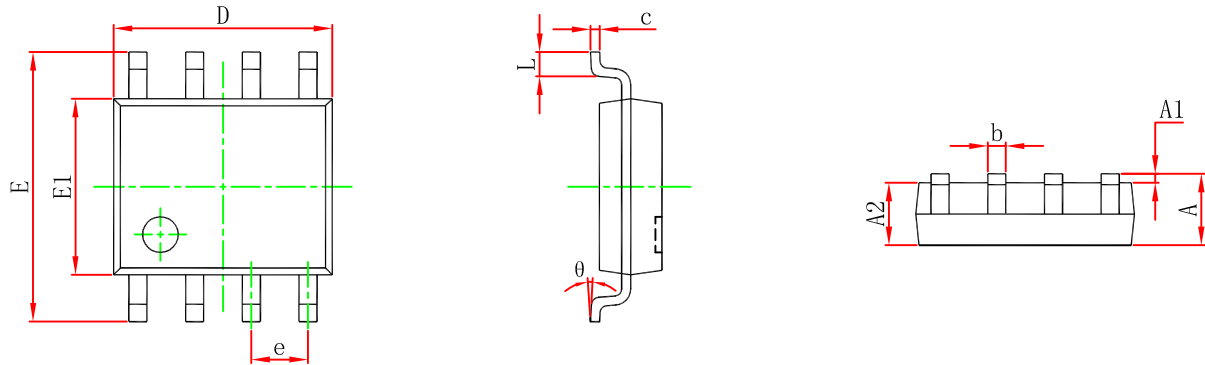


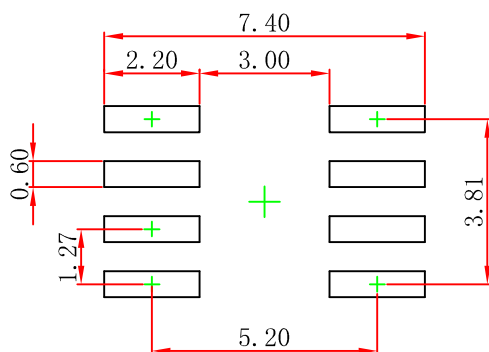
Fig.11 Unclamped Inductive Switching Waveform



## SOP-8(SO-8) Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.800	5.000	0.189	0.197
e	1.270 (BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°



### Note:

1. Controlling dimension; in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.



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